

## Features

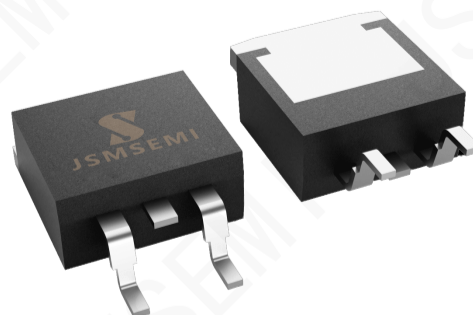
- Zero Forward/Reverse Recovery Current
- High Blocking Voltage
- High Frequency Operation
- Positive Temperature Coefficient on  $V_F$
- Temperature Independent Switching Behavior
- High surge current capability

## Benefits

- Higher System Efficiency
- Parallel Device Convenience without thermal runaway
- Higher Temperature Application
- No Switching loss
- Hard Switching & Higher Reliability
- Environmental Protection

## Applications

- Motor Drives
- Solar
- AC/DC converters
- DC/DC converters
- Uninterruptable power supplies



**D<sup>2</sup>PAK**



## Maximum Ratings ( $T_C=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	Value	Unit
Peak Repetitive Reverse Voltage	$V_{RRM}$		650	V
Peak Reverse Surge Voltage	$V_{RSM}$		650	V
DC Blocking Voltage	$V_R$		650	V
Continuous Forward Current	$I_F$	$T_C=25^{\circ}\text{C}$ $T_C=135^{\circ}\text{C}$ $T_C=150^{\circ}\text{C}$	32 14 10	A
Non repetitive Forward Surge Current	$I_{FSM}$	$T_C = 25^{\circ}\text{C}$ , $t_p=10\text{ ms}$ , Half Sine Pulse $T_C = 110^{\circ}\text{C}$ , $t_p=10\text{ ms}$ , Half Sine Pulse $T_C = 25^{\circ}\text{C}$ , $t_p=10\text{ }\mu\text{s}$ , Square	65 55 520	A
Repetitive peak Forward Surge Current	$I_{FRM}$	$T_C = 25^{\circ}\text{C}$ , $t_p=10\text{ ms}$ , Freq = 0.1Hz, 100 cycles, Half Sine Pulse $T_C = 110^{\circ}\text{C}$ , $t_p=10\text{ ms}$ , Freq = 0.1Hz, 100 cycles, Half Sine Pulse	55 45	A
Total power dissipation	$P_D$	$T_C=25^{\circ}\text{C}$	94	W
Operating Junction Temperature	$T_J$		-55 to 175	$^{\circ}\text{C}$
Storage Temperature	$T_{STG}$		-55 to 175	$^{\circ}\text{C}$

## Electrical Characteristics

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
DC Blocking Voltage	$V_{DC}$	$I_R = 250\mu A, T_J = 25^\circ C$	650			V
Forward Voltage	$V_F$	$I_F = 10A, T_J = 25^\circ C$		1.45	1.8	V
		$I_F = 10A, T_J = 125^\circ C$		1.6		
		$I_F = 10A, T_J = 175^\circ C$		1.7		V
Reverse Current	$I_R$	$V_R = 650V, T_J = 25^\circ C$		12	80	$\mu A$
		$V_R = 650V, T_J = 125^\circ C$		68		$\mu A$
		$V_R = 650V, T_J = 175^\circ C$		190		$\mu A$
Total Capacitive Charge	$Q_C$	$V_R = 400V, I_F = 10A, di/dt = 200A/\mu s, T_J = 25^\circ C$		23		nC
Total Capacitance	C	$V_R = 1V, T_J = 25^\circ C, Freq = 1MHz$		380		pF
		$V_R = 200V, T_J = 25^\circ C, Freq = 1MHz$		48		
		$V_R = 400V, T_J = 25^\circ C, Freq = 1MHz$		31		

Note: This is a majority carrier diode, so there is no reverse recovery charge

## Thermal Characteristics

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Thermal Resistance	$R_{th(j-c)}$	junction-case		1.6		$^\circ C/W$

## Ordering Information

Order number	Package	Marking	Operation Temperature Range	MSL Grade	Ship,Quantity	Green
SAIDK10S65C5ATMA1	TO-263	SC6D10065G	-55 to 175 $^\circ C$	1	T&R,1000	RoHS

## Typical Electrical Curves

Figure 1. Forward Characteristics

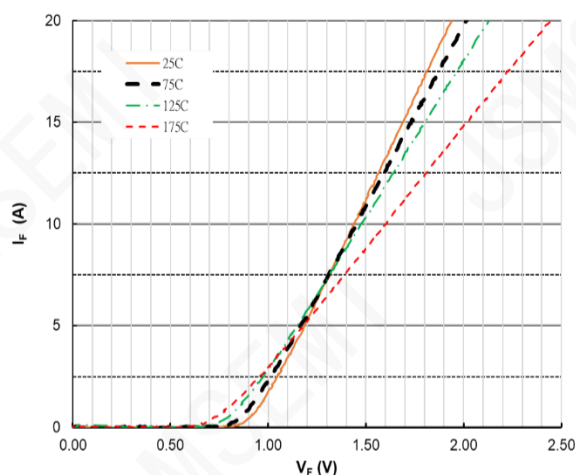


Figure 2. Forward Characteristics

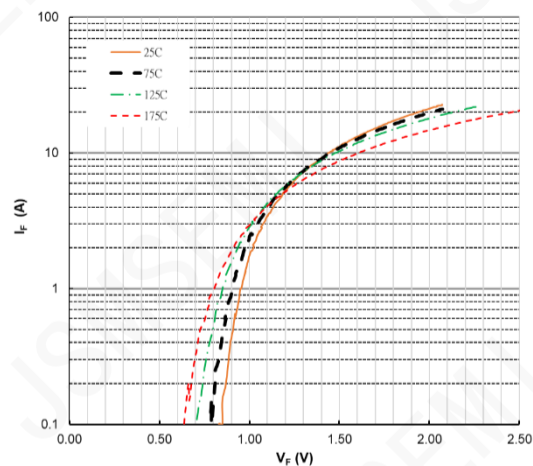


Figure 3. Reverse Characteristics

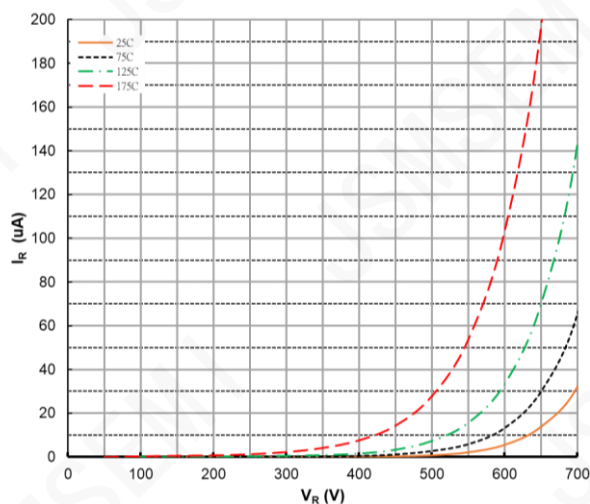


Figure 4. Power Derating

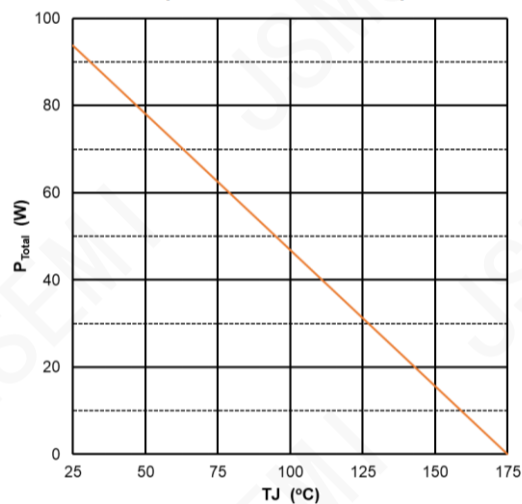


Figure 5. Capacitance vs Reverse Voltage

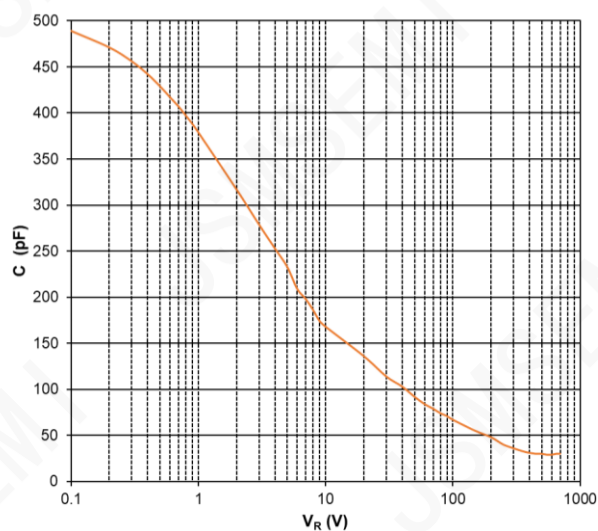
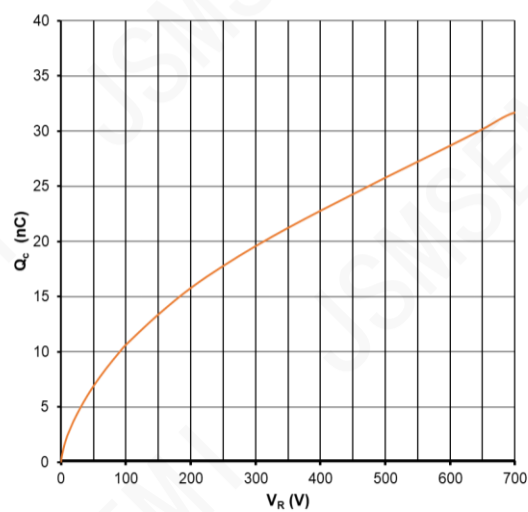
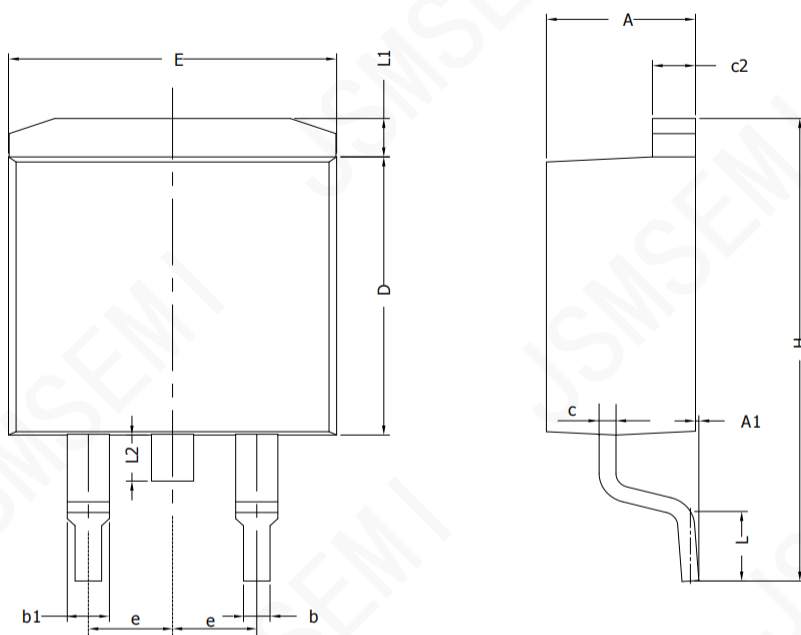


Figure 6. Recovery Charge vs Reverse Voltage



Package Outline: TO-263



SYMBOL	MIN	NOM	MAX
A	4.30	4.57	4.72
A1	0	0.10	0.25
b	0.71	0.81	0.91
c	0.30	---	0.60
c2	1.17	1.27	1.37
D	8.50	---	9.35
E	9.80	---	10.45
e	2.54BSC		
H	14.70	---	15.75
L	2.00	2.30	2.74
L1	1.12	1.27	1.42
L2	---	---	1.75

## Revision History

Rev.	Change	Date
V1.0	Initial version	2/23/2022

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